

INFORMATION DISCLOSURE STATEMENT BY APPLICANT <small>(use as many sheets as necessary)</small>				<i>Complete if Known</i>	
Application Number Filing Date First Named Inventor Group Art Unit Examiner Name		10/716,655 6/19/03 Scott K. Pozder et al. 287 HUNG VU			
		Sheet 1 of 1		Attorney Docket Number SC1295TP	

NON PATENT LITERATURE DOCUMENTS		
Examiner Initials*	Cite No. *	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.
VM	AC	LI et al., "Magnetic Nanoscale Dots on Colloid Crystal Surfaces," APPLIED PHYSICS LETTERS, Volume 76, Number 6, 2000 American Institute of Physics, pp. 748-750..
VM	AD	GROSS ET AL., "New Materials for High Performance No-Flow Underfill," 2002 INTERNATIONAL SYMPOSIUM ON MICROELECTRONICS, PP. 234-238.

Examiner Signature	HUNG VU	Date Considered	10/05/04
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EXAMINER: Initial reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English Language Translation is attached.

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